

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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 First Named Inventor Sherman
 Art Unit 1762
 Examiner Eric B. Fuller
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(Multiple sheets used when necessary)

SHEET 1 OF 1

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U.S. PATENT DOCUMENTS

Examiner Initials	Cite No.	Document Number Number - Kind Code (if known) Example: 1,234,567 B1	Publication Date MM-DD-YYYY	Name of Patentee or Applicant	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear

FOREIGN PATENT DOCUMENTS

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NON PATENT LITERATURE DOCUMENTS

Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ¹
KMS		MÖLSÄ et al., "Deposition of Cerium Dioxide Thin Films on Silicon Substrates by Atomic Layer Epitaxy," Mat. Res. Soc. Symp., Vol. 325, 1994 Materials Research Society, pp. 341-350	

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Examiner Signature /Kelly Stouffer/	Date Considered 02/28/2007
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